TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC3429

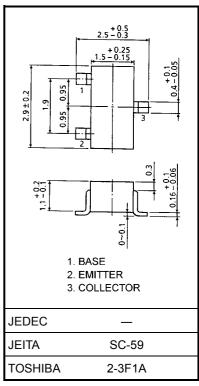
VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure
- NF = 1.5dB, $|S_{21e}|^2 = 16$ dB (f = 500 MHz)
- NF = 1.7dB, $|S_{21e}|^2 = 10.5dB$ (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage | V_{CBO} | 17 | V |
| Collector-emitter voltage | V _{CEO} | 12 | V |
| Emitter-base voltage | V _{EBO} | 3 | V |
| Collector current | IC | 70 | mA |
| Base current | ΙB | 30 | mA |
| Collector power dissipation | P _C | 150 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |



Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

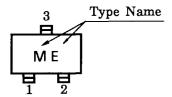
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------|-------------------------------------|---|-----|------|-----|------|
| Transition frequency | f _T | V _{CE} = 10 V, I _C = 20 mA | _ | 5 | _ | GHz |
| Insertion gain | S _{21e} ² (1) | $V_{CE} = 10 \text{ V}, I_{C} = 20 \text{ mA}, f = 500 \text{ MHz}$ | | 16 | | dB |
| | S _{21e} ² (2) | V _{CE} = 10 V, I _C = 20 mA, f = 1 GHz | _ | 10.5 | _ | |
| Noise figure | NF (1) | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 500 \text{ MHz}$ | _ | 1.5 | _ | dB |
| | NF (2) | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$ | | 1.7 | _ | UD |

Electrical Characteristics (Ta = 25°C)

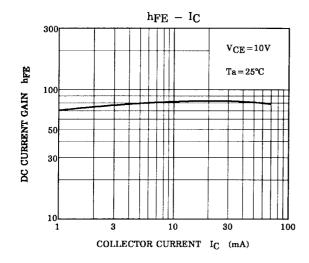
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|------------------|---|-----|------|-----|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = 10 \text{ V}, I_{E} = 0$ | _ | _ | 1 | μА |
| Emitter cut-off current | I _{EBO} | $V_{EB} = 1 \text{ V, } I_C = 0$ | _ | _ | 1 | μА |
| DC current gain | h _{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 20 \text{ mA}$ | 25 | _ | _ | |
| Collector output capacitance | C _{ob} | V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note) | _ | 0.85 | _ | pF |
| Reverse transfer capacitance | C _{re} | $V_{CB} = 10 \text{ V}, I_{E} = 0, I = 1 \text{ MINZ}$ (Note) | _ | 0.57 | _ | pF |

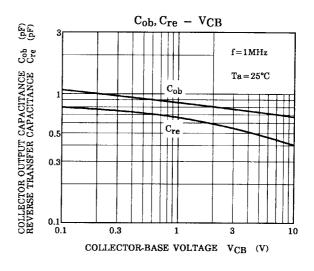
Note: C_{re} is measured by 3 terminal method with capacitance bridge.

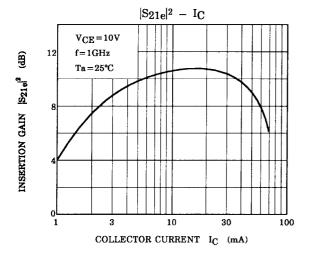
Marking

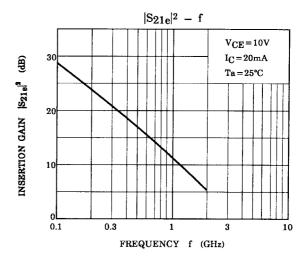


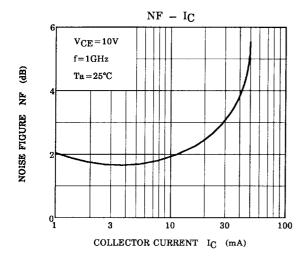
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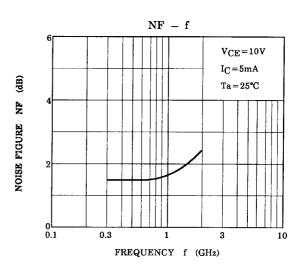








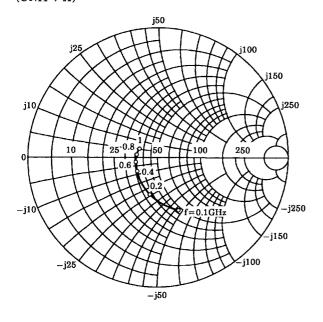


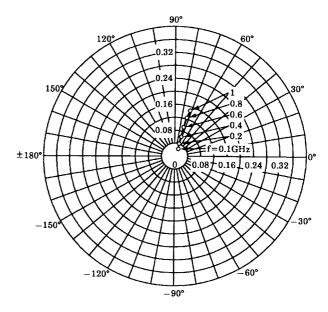


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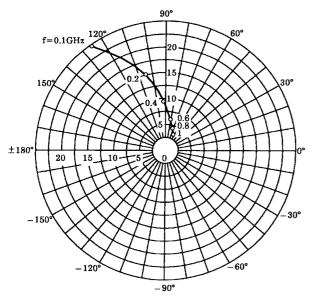
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 20 mA \\ Ta = 25 ^{\circ}C \\ (UNIT: \Omega) \end{array}$







 $\begin{array}{l} S_{21e} \\ V_{CE} = 10V \\ I_{C} = 20 mA \\ Ta = 25 ^{\circ}C \end{array}$



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